

产品规格书

Specifcation of products

产品名称: 三相整流桥模块

产品型号: MDS75A-T12

浙江世菱半导体有限公司
ZHEJIANG SHILING SEMICONDUCTOR CO., LTD.

地址: 浙江省 丽水市 莲都区

电话: (0578) 3615066

邮编: 323000

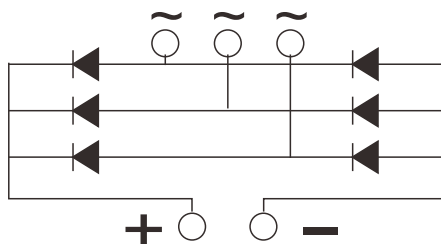
E-mail: smrshiling12@163.com

Http://www.smrshiling.com

拟制	审核	核准
蓝少波	陈一凡	曹剑龙

SYMBOL	CHARACTERISTIC	TEST CONDITIONS	T _j (°C)	VALUE			UNIT
				Min	Type	Max	
I _O	DC output current	Three-phase full wave rectifying circuit, T _C =100 °C	150			75	A
V _{RRM}	Repetitive peak reverse voltage	V _{RRM} tp=10ms V _{RSM} = V _{DRM} &V _{RRM} +200V	150	600		2200	V
I _{RRM}	Repetitive peak current	at V _{RRM}	150			8	mA
I _{FSM}	Surge forward current	10ms half sine wave	150			0.8	KA
I ² t	I ² T for fusing coordination	V _R =0.6V _{RRM}				3.2	A ² s*10 ³
V _{FO}	Threshold voltage		150			0.80	V
r _F	Forward slope resistance					7.0	mΩ
V _{FM}	Peak forward voltage	I _{FM} =75A	25			1.10	V
R _{th(j-c)}	Thermal resistance Junction to heatsink	Single side cooled				0.320	°C /W
V _{iso}	Isolation voltage	50Hz, R.M.S, t=1min, I _{iso} : 1mA (max)		3000			V
F _m	Terminal connection torque(M5)				4.0		N.m
	Mounting torque(M6)				5.0		N.m
T _{stg}	Stored temperature			-40		125	°C
W _t	Weight						g
Outline							

OUTLINE DRAWING & CIRCUIT DIAGRAM



Rating and Characteristic

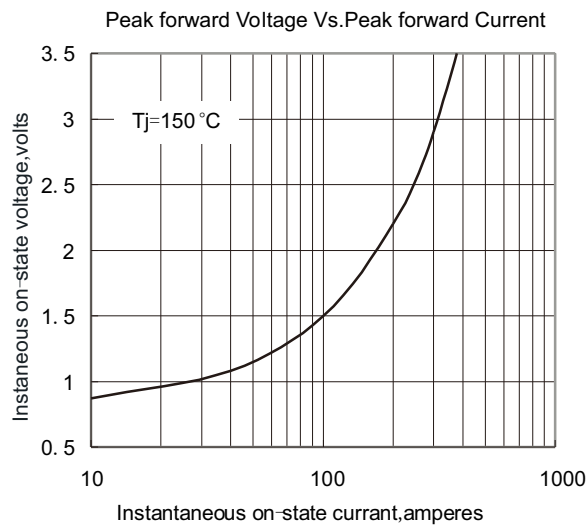


Fig. 1

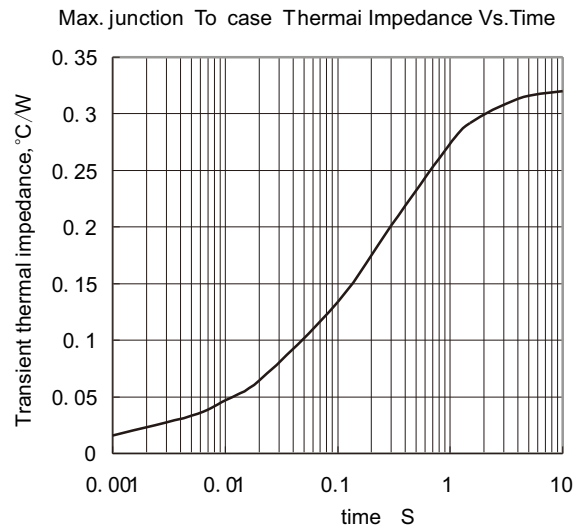


Fig. 2

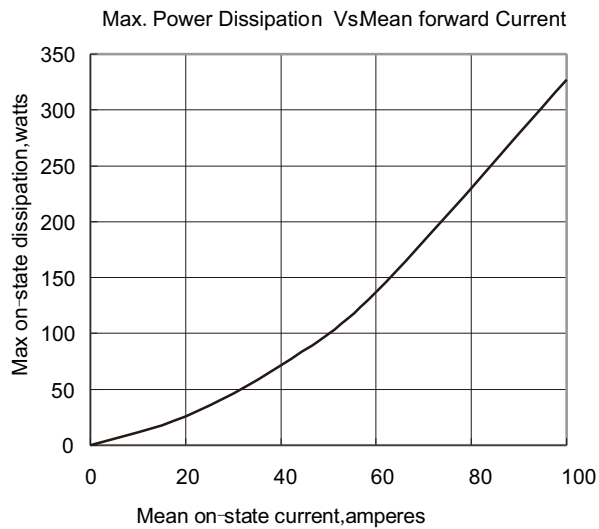


Fig. 3

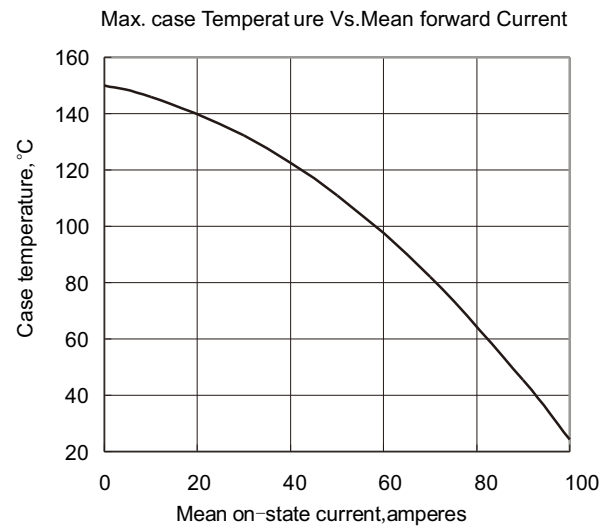


Fig. 4

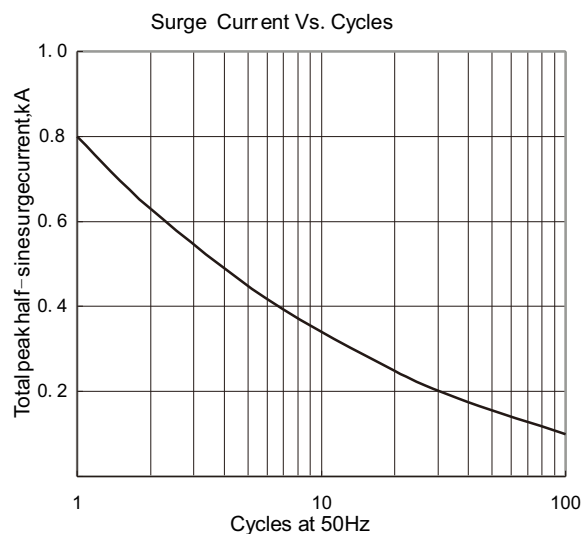


Fig. 5

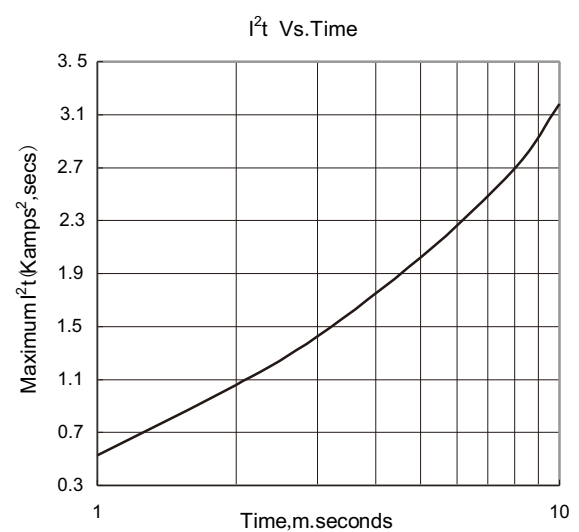
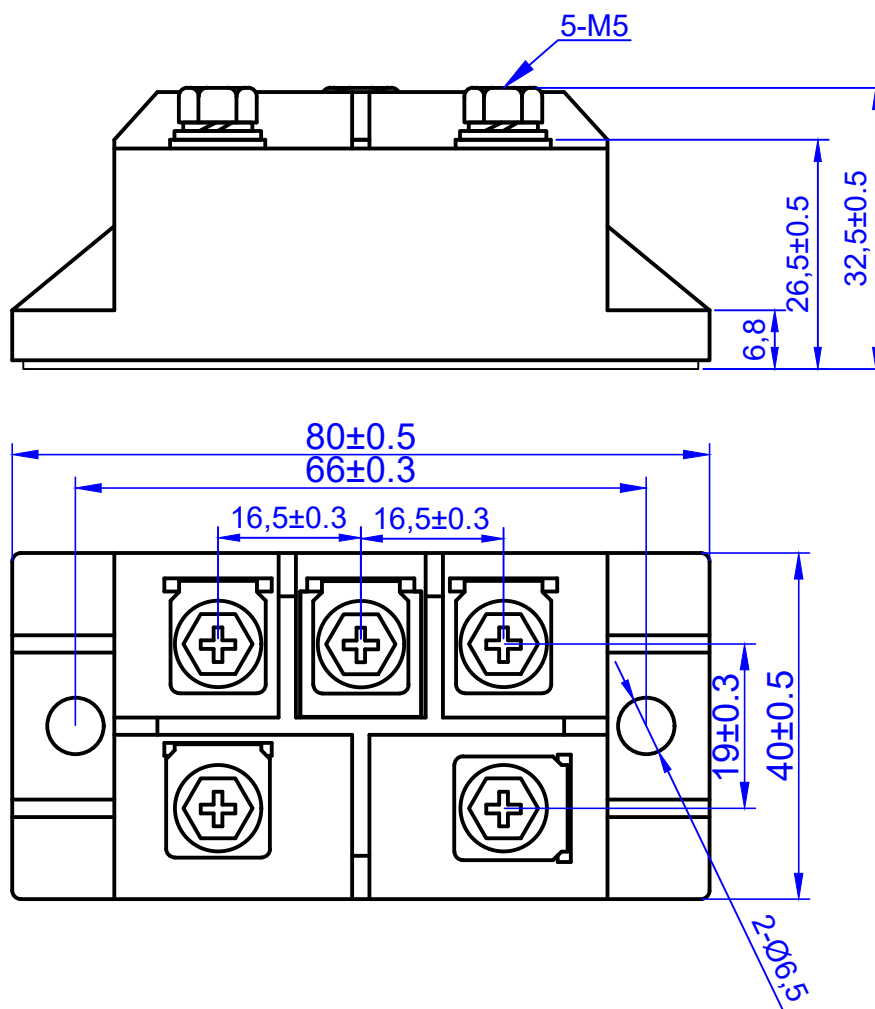


Fig. 6

Outside Dimension



Dimensions (mm)

